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ABSTRACT OF DISCLOSURE

An electronic device is provided using wiring comprising aluminum to prevent hillock or whisker from generating, wherein the wiring contains oxygen atoms at a concentration of  $8 \times 10^{18}$  atoms·cm<sup>-3</sup> or less, carbon atoms at a concentration of  $5 \times 10^{18}$  atoms·cm<sup>-3</sup> or less, and nitrogen atoms at a concentration of  $7 \times 10^{17}$  atoms·cm<sup>-3</sup> or less; furthermore, a silicon nitride film is formed on the aluminum gate, and an anodic oxide film is formed on the side planes thereof.

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